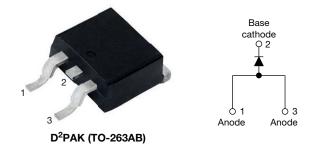


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High Voltage Surface Mount Input Rectifier Diode, 20 A



PRIMARY CHARACT	PRIMARY CHARACTERISTICS				
I _{F(AV)}	20 A				
V _R	800 V, 1200 V				
V _F at I _F	1.1 V				
I _{FSM}	300 A				
T _J max.	150 °C				
Package	D ² PAK (TO-263AB)				
Circuit configuration	Single				

FEATURES

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-20ETS...S-M3 rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 $^{\circ}$ C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS						
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS						
Capacitive input filter $T_A = 55 \text{ °C}$, $T_J = 125 \text{ °C}$ common heatsink of 1 °C/W	16.3	21	А			

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	DL CHARACTERISTICS VALUES UNITS							
I _{F(AV)}	Sinusoidal waveform	20	A					
V _{RRM}		800/1200	V					
I _{FSM}		300	A					
V _F	20 A, T _J = 25 °C	1.1	V					
Тј		-40 to +150	°C					

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
VS-20ETS08S-M3	800	900	1				
VS-20ETS12S-M3	1200	1300	I				

ABSOLUTE MAXIMUM RATING	S				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum average forward current	I _{F(AV)}	T_{C} = 105 °C, 180° conduction half sine wave	20		
Maximum peak one cycle non-repetitive surge current		10 ms sine pulse, rated V _{RRM} applied	250	А	
	I _{FSM}	10 ms sine pulse, no voltage reapplied	300		
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	316	A ² s	
Maximum Pt for fusing	1-1	10 ms sine pulse, no voltage reapplied	442	A-2	
Maximum I ² √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s	

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COMPLIANT HALOGEN

FREE



VS-20ETS08S-M3, VS-20ETS12S-M3 Series

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST (CONDITIONS	VALUES	UNITS		
Maximum forward voltage drop	V _{FM}	20 A, T _J = 25 °C		1.1	V		
Forward slope resistance	r _t	T _{.1} = 150 °C		10.4	mΩ		
Threshold voltage	V _{F(TO)}	1J = 150 C	0.85	V			
Maximum reverse leakage current	le	T _J = 25 °C	V _B = Rated V _{BBM}	0.1	mA		
Maximum reverse leakage current	IRM	T _J = 150 °C	VR = naleu VRRM	1.0	ШA		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SY	MBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature	re range 🛛 T _J	, T _{Stg}		-40 to +150	°C			
Maximum thermal resistance, junction to case	F	R _{thJC}	DC operation	1.3				
Maximum thermal resistance, junction to ambient	Rt	hJA ⁽¹⁾	For D ² PAK version	62	°C/W			
Typical thermal resistance, case to heatsink	F	R _{thCS}	Mounting surface, smooth, and greased	0.5				
Approvimate weight				2	g			
Approximate weight				0.07	oz.			
	nimum			6.0 (5.0)	kgf · cm			
Mounting torque maximum				12 (10)	(lbf · in)			
Mand the startes			Case style D ² PAK (TO-263AB)	20ET	S08S			
Marking device			Case signe D-FAR (10-203AB)	20ET:	S12S			

Note

(1) When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W

For recommended footprint and soldering techniques refer to application note #AN-994

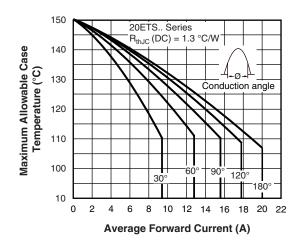


Fig. 1 - Current Rating Characteristics

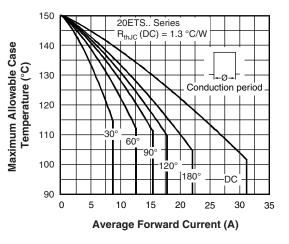


Fig. 2 - Current Rating Characteristics



VS-20ETS08S-M3, VS-20ETS12S-M3 Series

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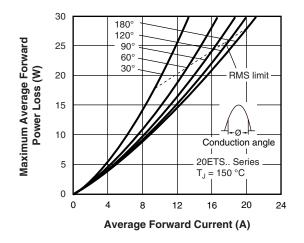


Fig. 3 - Forward Power Loss Characteristics

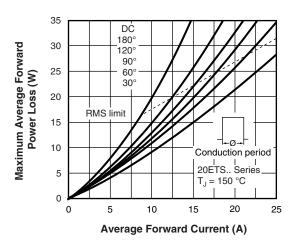


Fig. 4 - Forward Power Loss Characteristics



Number of Equal Amplitude Half Cycle Current Pulse (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

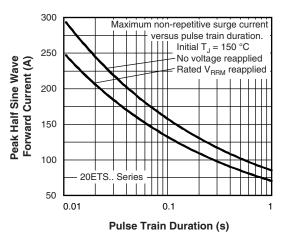
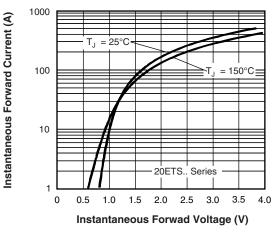
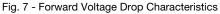


Fig. 6 - Maximum Non-Repetitive Surge Current







VS-20ETS08S-M3, VS-20ETS12S-M3 Series

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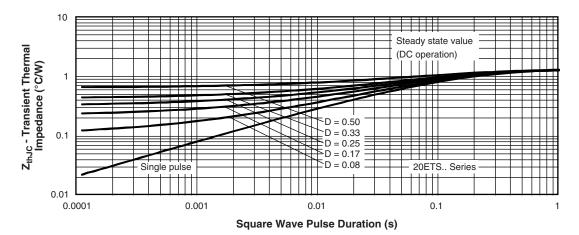


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code	VS-	20	Е	т	s	12	S	TRL	-M3
	1	2	3	4	5	6	7	8	9
	1 · 2 · 3 ·	- Cur - Circ E - Pac	nay Sen rent rati cuit conf = single kage: = D ² PA	ng (20 = iguratior	= 20 A) n	oduct			
	5 - 6 - 7 - 8 - 9 -	S Voli S = • No • TF • TF	e of silic = stand tage coo surface one = tu RL = tap RR = tap S = halog	ard reco le x 100 mounta be e and re be and re	eel (left eel (righ	oriented	ed)	12 = 1	800 V 200 V



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ORDERING INFORMATION (Example)							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-20ETS08S-M3	50	Antistatic plastic tube					
VS-20ETS08STRR-M3	800	13" diameter reel					
VS-20ETS08STRL-M3	800	13" diameter reel					
VS-20ETS12S-M3	50	Antistatic plastic tube					
VS-20ETS12STRR-M3	800	13" diameter reel					
VS-20ETS12STRL-M3	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96164			
Part marking information	www.vishay.com/doc?95444			
Packaging information	www.vishay.com/doc?96424			
SPICE model	www.vishay.com/doc?97266			

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D²PAK

DIMENSIONS in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN. MAX.		NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010 BSC		
L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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